

Vacuum Soldering System for processing also for contaminating processes



VSS-300-CAB

- For substrate size up to 300 mm x 300 mm x 65 mm
- Ramp up rate up to 150 K/min
- SIMATIC® Controller with 7" touch panel
- Vacuum up to 10^{-3} hPa (opt. 10^{-6} hPa)
- Process gas line with Mass Flow Controller for Nitrogen
- Temperature up to 450 °C (opt. up to 650 °C)
- Vertical automatical open/close

Application

- Small foot print
- 3 heating zones programmable
- with rack
- with integrated universal heat exchanger (cooling tank 80 l)
- integrated in process control
- secondary water circuit 4 – 5 bars
- use with purified water

Features

- Precise ramp up and fast ramp down rates
- Up to 4 gas lines (MFC)
- Heated by Infrared lamps
- SIMATIC® Controller
- 50 programs with 50 steps each
- Top and bottom heating (selection by Software)

VSS-300

- Vacuum Solder System
- Programmable temperature profiles
- Record of process data
- Process in different gas atmospheres

The VSS-300 Vacuum Process Oven

The VSS-300 Reflow Solder System is an excellent tool for various solder processes up to 300 mm diameter wafer or 300 mm x 300 mm substrate size and 65 mm height (Option: EH with 120 mm height.)

Some examples for applications:

Laboratory furnace for all kind of developers implementing and researching new processes, prototype research, environmental research purposes and for small pre-series or series.

Process Gases

The VSS-300 can be used with standard process gases, like Nitrogen, Oxygen, Forming Gas. The chamber is sealed and can easily be cleaned.

Gas flow control

One gas line with Mass Flow Controller (MFC) for Nitrogen (5 nlm = norm liter per minute) is default, three more gas lines (Option: MFC) are possible.

Vacuum

The system is vacuum capable of up to 10^{-3} hPa (optionally up to 10^{-6} hPa).

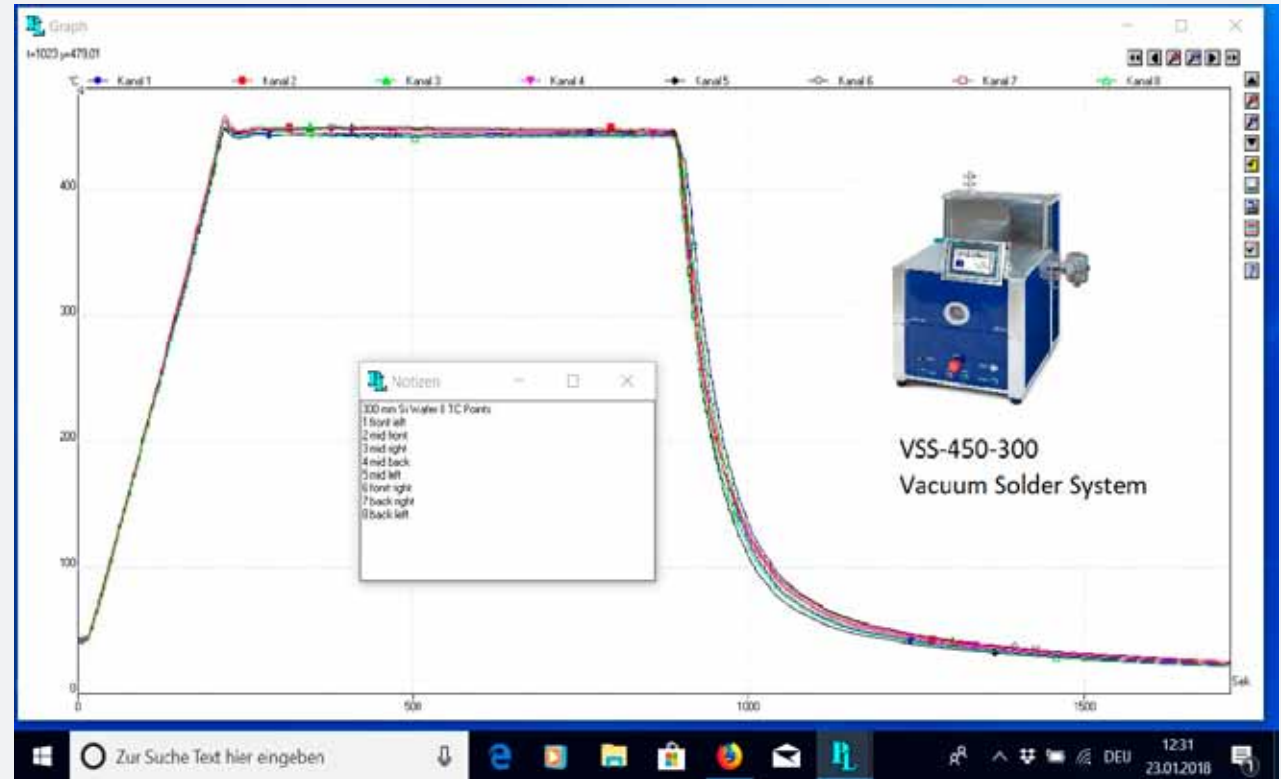
Heating

The maximal achievable temperature is 400 °C (opt. 650 °C). Key features are precisely controlled fast ramp-up (150 K/min) and excellent ramp-down rates (depend on temperature and loading)

Temperature distribution

The VSS-300 allows an excellent temperature distribution and homogeneity. Optionally a graphite susceptor can be inserted on the quartz bottom plate.

VSS-300 Example for a standard temperature profile with VSS-450-300



Programming

The VSS-300 is controlled by SPS SIMATIC® controller. A 7" touch panel allows a very comfortable programming and control of the process. There can be saved up to 50 programs with 50 steps each (unlimited programs can be down- and uploaded from an external data storage).

Process control

The software allows the permanent monitoring, readout and analysis of

- temperature
- process gas flow
- cooling water level status
- pressure value and status

Cooling process

The hot plate is active cooled with homogenous cooling from both sides.

Others

An interlock function as well as an Emergency-OFF-Button (EMO) are default.

Special

This oven can also be integrated into a production line. The chamber open/close is realized by push button operation.



Specification

Max. part size	300 mm dia. or 300 mm x 300 mm
Chamber material	Aluminium chamber (chamber area: 350 mm x 350 mm) inclusive quartz glass bottom plate
Chamber height	70 mm (optional: 120 mm)
Vacuum capability	Up to 10 ⁻³ hPa (optional up to 10 ⁻⁶ hPa)
Temperature max.	450 °C (higher temp. on request)
Temp. uniformity	≤ 1 % of set temperature (on a 200 mm wafer) (e.g. ± 3 K @ 300 °C)
Heating	Bottom Heating: Infrared lamps cross aligned (18 kW)
Ramp up rate	150 K/min
Ramp down rate	T = 450 °C > 200 °C: 90 K/min, T = 200 °C > 100 °C: 60 K/min
Flow Controller	One Mass Flow Controller for 5 nlm (=norm liter per minute) as default, up to 3 more Mass Flow Controllers are available as option
Controller	SIMATIC® controller, 50 programs with 50 steps each
Chamber cooling	By internal water cooling system with 80 l tank volume
Substrate Cooling	By Nitrogen Gas

Technical Data

Dimension oven	600 mm x 780 mm 1730 mm (W x D x H)
Weight	170 kg
Electrical connection	400/230 V, 18 kW

No. Options:

Additional process gas lines:	
1	VSS-MFC-Ar-2nlm Additional process gas line for Argon (Ar) gas controlled by Mass Flow Controller
2	VSS-MFC-O2-2nlm Additional process gas line for Oxygen (O ₂) gas controlled by Mass Flow Controller
3	VSS-MFC-FG-2nlm Additional process gas line for Forming Gas (max. 10 % H ₂ /N ₂) gas controlled by Mass Flow Controller
Formic acid module and trap:	
4	FA II Upgrade with integrated formic acid module with individually controlled process gas line
5	FA III Upgrade with integrated formic acid module (process gas line shared with base VSS system)
6	FA IV Formic acid module with separate gas line and automatic refilling
7	FA-T Trap for formic acid vapors
8	FA-T-2 Double Trap for formic acid
Flux options:	
9	VSS-FluxHeat
10	VSS-FT Flux trap
11	VSS-FT-2 Flux trap
Height and lift pins options:	
12	VSS-EH Extended chamber height up to 120 mm
13	VSS-LiftPins Upgrade with Lift pins for lifting up of single wafer (150 mm, 200 mm or 300 mm diameter)
Hydrogen gas options	
14	H2 Hydrogen option for use of pure hydrogen gas (100% H ₂)
15	H2S Safety hood
Additional thermocouples:	
16	TC I Upgrade with additional (flexible) thermocouple (not connected to process control, for external data logging)
17	TC II additional thermocouple to measure on device (plugged in chamber); for external measurement tool (max. 4 pcs)
Vacuum options (not including vacuum pumps):	
18	VAC I Vacuum basic up to 3 hPa incl. vacuum sensor and valve
19	VAC II Vacuum comfort up to 10 ⁻³ hPa incl. vacuum sensor and valve
Interfaces:	
20	VSS-RC Remote control of top cover opening and closing, including connection to safety of external cabinet
21	VSS-SI Serial interface between VSS system and external PC using USB 2.0 port and through USB 2.0 cable
Measurement options:	
22	MM Moisture measurement
23	OxAtAn Atmospheric oxygen analyser
Other options:	
24	CAB Cabinet with integrated Universal Heat Exchanger (UHE)
25	PT Upgrade with 3 colors pat light
26	VSS-QP Additional quartz glass plate at top
27	VSS-ET Extension of max temperature to 650 °C
Accessories (vacuum pumps, chiller):	
28	MP Membrane/diaphragm pump (not chemically resistant)
29	MPC Chemically resistant membrane/diaphragm pump
30	RVP Rotary vane pump for vacuum up to 10exp. ⁻³ with oil filter
31	WC III Closed loop water cooling system
32	UHE Universal Heat exchanger (as alternative to WC-III, requires cooling water for its primary side)

